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# DIODES, POWER RECTIFIER, HIGH EFFICIENCY, FAST RECOVERY

## **BASED ON TYPE BYV52-200**

ESCC Detail Specification No. 5103/030



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## **DOCUMENTATION CHANGE NOTICE**

(Refer to https://escies.org for ESCC DCR content)

| DCR No. | CHANGE DESCRIPTION                                     |
|---------|--|
| 1218    | Specification upissued to incorporate changes per DCR. |



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#### 1 <u>GENERAL</u>

#### 1.1 <u>SCOPE</u>

This specification details the ratings, physical and electrical characteristics and test and inspection data for the component type variants and/or the range of components specified below. It supplements the requirements of, and shall be read in conjunction with, the ESCC Generic Specification listed under Applicable Documents.

#### 1.2 <u>APPLICABLE DOCUMENTS</u>

The following documents form part of this specification and shall be read in conjunction with it:

- (a) ESCC Generic Specification No. 5000
- (b) MIL-STD-750, Test Methods and Procedures for Semiconductor Devices

#### 1.3 TERMS, DEFINITIONS, ABBREVIATIONS, SYMBOLS AND UNITS

For the purpose of this specification, the terms, definitions, abbreviations, symbols and units specified in ESCC Basic Specification No. 21300 shall apply.

#### 1.4 THE ESCC COMPONENT NUMBER AND COMPONENT TYPE VARIANTS

#### 1.4.1 <u>The ESCC Component Number</u>

The ESCC Component Number shall be constituted as follows:

Example: 510303001

- Detail Specification Reference: 5103030
- Component Type Variant Number: 01 (as required)

#### 1.4.2 <u>Component Type Variants</u>

The component type variants applicable to this specification are as follows:

| Variant<br>Number | Based on Type | Case   | Description  | Lead Material and<br>Finish | Weight<br>max g |
|-------------------|---------------|--------|--------------|-----------------------------|-----------------|
| 01                | BYV52-200     | TO-254 | Single diode | H9                          | 10              |
| 02                | BYV52-200     | TO-254 | Single diode | H14                         | 10              |
| 03                | BYV52-200     | TO-254 | Single diode | H4                          | 10              |

The lead material and finish shall be in accordance with the requirements of ESCC Basic Specification No. 23500.



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#### 1.5 MAXIMUM RATINGS

The maximum ratings shall not be exceeded at any time during use or storage.

Maximum ratings shall only be exceeded during testing to the extent specified in this specification and when stipulated in Test Methods and Procedures of the ESCC Generic Specification.

| Characteristics                                   | Symbols              | Maximum Ratings | Unit | Remarks                  |
|---|----------------------|-----------------|------|--------------------------|
| Forward Surge Current                             | IFSM                 | 400             | А    | Note 1                   |
| Repetitive Peak Reverse<br>Voltage                | Vrrm                 | 200             | V    | Note 2                   |
| Average Output Rectified<br>Current               | lo                   | 30              | A    | 50% Duty Cycle<br>Note 3 |
| RMS Forward Current                               | I <sub>F(rms)</sub>  | 30              | А    |                          |
| Operating Temperature<br>Range (Case Temperature) | T <sub>op</sub>      | -55 to +150     | °C   | Note 4                   |
| Junction Temperature                              | Tj                   | +150            | °C   |                          |
| Storage Temperature Range                         | T <sub>stg</sub>     | -55 to +150     | °C   | Note 4                   |
| Soldering Temperature                             | T <sub>sol</sub>     | +260            | °C   | Note 5                   |
| Thermal Resistance,<br>Junction to Case           | R <sub>th(j-c)</sub> | 0.9             | °C/W | Note 6                   |

#### NOTES:

- 1. Sinusoidal pulse of 10ms duration.
- 2. Pulsed, duration 5ms, f = 50Hz.
- 3. At  $T_{case} > +120^{\circ}$ C, derate linearly to 0A at +150°C.
- 4. For Variants with hot solder dip lead finish all testing performed at Tamb > +125°C shall be carried out in a 100% inert atmosphere.
- 5. Duration 10 seconds maximum at a distance of not less than 1.5mm from the device body and the same lead shall not be resoldered until 3 minutes have elapsed.
- 6. Package mounted on an infinite heatsink.

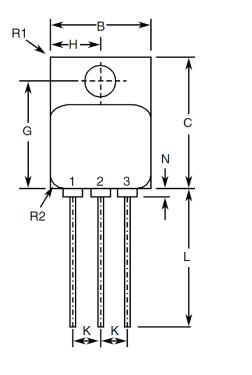
#### 1.6 HANDLING PRECAUTIONS

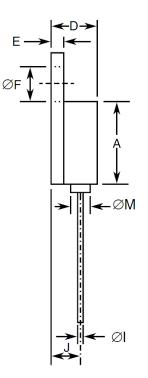
The TO-254 package contains Beryllium Oxide (BeO) and therefore it must not be ground, machined, sandblasted or subjected to any mechanical operation which will produce dust. The case must not be subjected to any chemical process (e.g. etching) which will produce fumes.



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#### 1.7 <u>PHYSICAL DIMENSIONS AND TERMINAL IDENTIFICATION</u> <u>METAL FLANGE MOUNT PACKAGE (TO-254) - 3 LEAD</u>





| Symbols | Dimensi      | ons mm | Notes |
|---------|--------------|--------|-------|
|         | Min          | Max    |       |
| A       | 13.59        | 13.84  |       |
| В       | 13.59        | 13.84  |       |
| С       | 20.07        | 20.32  |       |
| D       | 6.3          | 6.7    |       |
| E       | 1            | 1.35   |       |
| ØF      | 3.5          | 3.9    |       |
| G       | 16.89        | 17.4   |       |
| Н       | 6.86         | BSC    |       |
| ØI      | 0.89         | 1.14   | 2     |
| J       | 3.81         | BSC    |       |
| К       | 3.81         | BSC    |       |
| L       | 12.95        | 14.5   |       |
| ØM      | 3.05 Typical |        | 2     |
| N       | -            | 0.71   | 2     |
| R1      | -            | 1      | 3     |
| R2      | 1.65 T       | ypical | 4     |





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#### NOTES:

- 1. The terminal identification is specified by the components geometry. See Para. 1.8 Functional Diagram for the terminal connections.
- 2. 3 places.
- 3. Radius of heatsink flange corner, 4 places.
- 4. Radius of body corner, 4 places.

#### 1.8 <u>FUNCTIONAL DIAGRAM</u>

Terminal 1: Cathode Terminal 2: Not connected Terminal 3: Anode



#### NOTES:

1. The case is not connected to any lead.

1.9 <u>MATERIALS AND FINISHES</u> Materials and finishes shall be as follows:

- (a) Case The case shall be hermetically sealed and have a metal body. The leads pass through ceramic eyelets brazed into the frame and the lid shall be welded.
- (b) Leads As specified in Para. 1.4.2.

#### 2 <u>REQUIREMENTS</u>

2.1 <u>GENERAL</u>

The complete requirements for procurement of the components specified herein are as stated in this specification and the ESCC Generic Specification. Permitted deviations from the Generic Specification, applicable to this specification only, are listed below.

Permitted deviations from the Generic Specification and this Detail Specification, formally agreed with specific Manufacturers on the basis that the alternative requirements are equivalent to the ESCC requirement and do not affect the component's reliability, are listed in the appendices attached to this specification.

2.1.1 <u>Deviations from the Generic Specification</u> None.



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#### 2.2 <u>MARKING</u>

The marking shall be in accordance with the requirements of ESCC Basic Specification No. 21700 and as follows.

The information to be marked on the component shall be:

- (a) The ESCC qualified components symbol (for ESCC qualified components only).
- (b) The ESCC Component Number (see Para. 1.4.1).
- (c) Traceability information.
- (d) Warning sign for Beryllium Oxide.

#### 2.3 CASE ISOLATION

Case Isolation shall be performed as specified in the ESCC Generic Specification and as follows:

- Test Conditions:
  - o Test voltage: 500Vdc
  - o Duration of application of test voltage: 1s
  - Points of application of test voltage: between case metal tab and all terminals connected together.
  - o Maximum leakage current: 10nA

#### 2.4 <u>TERMINAL STRENGTH</u>

The test conditions for Terminal Strength, tested as specified in the ESCC Generic Specification, shall be as follows:

Test Condition: A, tension, with an applied force of 10N for a duration of 10s.

## 2.5 <u>ELECTRICAL MEASUREMENTS AT ROOM, HIGH AND LOW TEMPERATURES</u> Electrical measurements shall be performed at room, high and low temperatures. Consolidated notes are given in Para. 2.5.3.

2.5.1 <u>Room Temperature Electrical Measurements</u> The measurements shall be performed at  $T_{amb} = +22 \pm 3^{\circ}C$ .

| Characteristics      | eristics Symbols MIL-STD-750 Test Conditions |             |  |     | nits | Units |
|----------------------|--|-------------|--|-----|------|-------|
|                      |  | Test Method |  | Min | Max  |       |
| Reverse Current      | IR   | 4016        | DC Method<br>V <sub>R</sub> = 200V           | -   | 25   | μA    |
| Forward Voltage      | V <sub>F1</sub>                              | 4011        | Pulse Method<br>I <sub>F</sub> = 20A, Note 1 | -   | 1.01 | V     |
|                      | V <sub>F2</sub>                              | 4011        | Pulse Method $I_F = 30A$ , Note 1            | -   | 1.15 | V     |
| Breakdown<br>Voltage | V <sub>(BR)</sub>                            | 4021        | I <sub>R</sub> = 100µA                       | 200 | -    | V     |
| Capacitance          | С  | 4001        | V <sub>R</sub> = 10V<br>f = 1MHz             | -   | 400  | pF    |



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| Characteristics                           | Symbols  | MIL-STD-750 | Test Conditions  | Lin | nits                            | Units |
|---|----------|-------------|--|-----|---------------------------------|-------|
|   |          | Test Method |  | Min | Max                             |       |
| Reverse Recovery<br>Time                  | trr      | 4031        | Test Condition A<br>$I_F = 1A$<br>$V_R = 30V$<br>$dI_F/dt = -50A/\mu s$  | -   | 55                              | ns    |
| Thermal<br>Impedance,<br>Junction to Case | Zth(j-c) | 3101        | $I_{H} = 15 \text{ to } 40\text{A}$<br>$t_{H} = 50\text{ms}$<br>$I_{M} = 50\text{mA}$<br>$t_{md} = 100\mu\text{s}$<br>Note 2 | •   | ate ΔV <sub>F</sub> ,<br>ote 3) | °C/W  |

#### 2.5.2 High and Low Temperatures Electrical Measurements

| Characteristics   | Symbols         | MIL-STD-750 | Test Conditions  | Limits |      | Units |
|-------------------|-----------------|-------------|--|--------|------|-------|
|                   |                 | Test Method | Note 4   | Min    | Max  |       |
| Reverse Current   | IR              | 4016        | T <sub>case</sub> = +125 (+0 -5)°C<br>DC Method<br>V <sub>R</sub> = 200V           | -      | 15   | mA    |
| Forward Voltage 1 | V <sub>F1</sub> | 4011        | $T_{case} = +125 (+0 -5)^{\circ}C$<br>Pulse Method<br>I <sub>F</sub> = 20A, Note 1 | -      | 0.95 | V     |
|                   |                 |             | $T_{case} = -55 (+5 -0)^{\circ}C$<br>Pulse Method<br>I <sub>F</sub> = 20A, Note 1  | -      | 1.15 | V     |

- 2.5.3 Notes to Electrical Measurement Tables
  - 1. Pulse Width  $\leq$  680µs, Duty Cycle  $\leq$  2%.
  - 2. Performed only during Screening Tests Parameter Drift Values (Initial Measurements), go-no-go.
  - 3. The limits for  $\Delta V_F$  shall be defined by the Manufacturer on every lot in accordance with MIL-STD-750 Method 3101 and shall guarantee the  $R_{th(j-c)}$  limits specified in Para. 1.5 Maximum Ratings.
  - 4. Read and record measurements shall be performed on a sample of 5 components with 0 failures allowed. Alternatively a 100% inspection may be performed.



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#### 2.6 PARAMETER DRIFT VALUES

Unless otherwise specified, the measurements shall be performed at  $T_{amb}$  = +22 ±3°C.

The test methods and test conditions shall be as per the corresponding test defined in Para. 2.5.1, Room Temperature Electrical Measurements.

The drift values ( $\Delta$ ) shall not be exceeded for each characteristic specified. The corresponding absolute limit values for each characteristic shall not be exceeded.

| Characteristics   | Symbols         |                       | Limits |          | Units |
|-------------------|-----------------|-----------------------|--------|----------|-------|
|                   |                 | Drift                 | Abso   | Absolute |       |
|                   |                 | Value<br>Δ            | Min    | Max      |       |
| Reverse Current   | I <sub>R</sub>  | ±3<br>or (1)<br>±100% | -      | 25       | mA    |
| Forward Voltage 1 | V <sub>F1</sub> | ±0.05                 | -      | 1.01     | V     |

#### NOTES:

1. Whichever is the greater referred to the initial value.

#### 2.7 INTERMEDIATE AND END-POINT ELECTRICAL MEASUREMENTS

Unless otherwise specified, the measurements shall be performed at  $T_{amb} = +22 \pm 3^{\circ}C$ .

The test methods and test conditions shall be as per the corresponding test defined in Para. 2.5.1, Room Temperature Electrical Measurements.

The limit values for each characteristic shall not be exceeded.

| Characteristics   | Symbols         | Limits |      | Units |
|-------------------|-----------------|--------|------|-------|
|                   |                 | Min    | Max  |       |
| Reverse Current   | I <sub>R</sub>  | -      | 25   | μA    |
| Forward Voltage 1 | V <sub>F1</sub> | -      | 1.01 | V     |

#### 2.8 HIGH TEMPERATURE REVERSE BIAS BURN-IN CONDITIONS

| Characteristics     | Symbols   | Limits       | Units |
|---------------------|-----------|--------------|-------|
| Ambient Temperature | $T_{amb}$ | +150 (+0 -5) | °C    |
| Reverse Voltage     | VR        | 160          | V     |
| Duration            | t         | ≥ 48         | hours |



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#### 2.9 POWER BURN-IN CONDITIONS

| Characteristics                  | Symbols           | Test Conditions  | Units |
|----------------------------------|-------------------|------------------|-------|
| Case Temperature                 | T <sub>case</sub> | +125 ±15, Note 1 | °C    |
| Junction Temperature             | Tj                | +150 (+0 -5)     | °C    |
| Average Output Rectified Current | lo                | ≥ 15, Note 1     | A     |

#### NOTES:

1. The case temperature and/or output current may be adjusted, within their given limit ranges, to attain the specified junction temperature.

#### 2.10 OPERATING LIFE CONDITIONS

The conditions shall be as specified in Para. 2.9 Power Burn-in Conditions.



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### APPENDIX 'A'

#### AGREED DEVIATIONS FOR STMICROELECTRONICS (F)

| ITEMS AFFECTED  | DESCRIPTION OF DEVIATIONS  |
|---|--|
| Para. 2.1.1, Deviations<br>from the Generic<br>Specification: Deviations<br>from Production Control -<br>Chart F2 | Special In-Process Controls - Internal Visual Inspection.<br>Wedge bonds equal to 1.1 wire diameters are acceptable for bonding<br>with a V-Groove tool. |
| Para. 2.1.1, Deviations<br>from the Generic<br>Specification: Deviations<br>from Screening Tests -<br>Chart F3    | Solderability is not applicable unless specifically stipulated in the Purchase Order.  |